NSN 5961-01-434-7583

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-434-7583 **Inclosure Material:** Metal **Function For Which Designed:** Rectifier **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1.2 reverse voltage, peak **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Thread Series Designator:** Unf Shelf Life: N/a **Unit Of Measure:** Demilitarization:

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